EN: This Datasheet/Document is presented by the manufacturer.

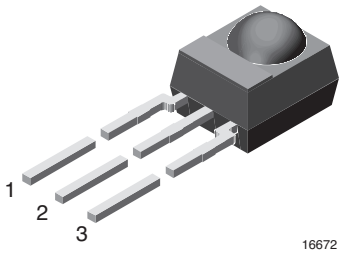
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IR Receiver Modules for Remote Control Systems

Description

The TSOP322.. - series are miniaturized receivers for infrared remote control systems. PIN diode and preamplifier are assembled on lead frame, the epoxy package is designed as IR filter.

The demodulated output signal can directly be decoded by a microprocessor. TSOP322.. is the standard IR remote control receiver series for 3 V supply voltage, supporting all major transmission codes.



Features

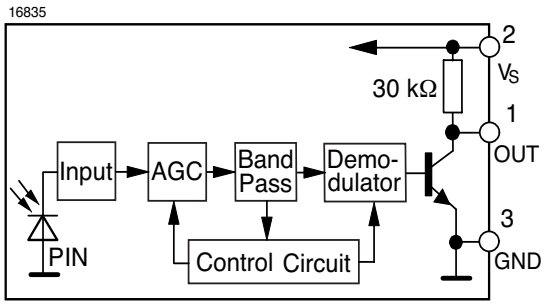
- Photo detector and preamplifier in one package
- Internal filter for PCM frequency
- Improved shielding against electrical field disturbance
- TTL and CMOS compatibility
- Output active low
- Supply voltage: 2.7 V to 5.5 V
- Improved immunity against ambient light

Mechanical Data

Pinning:

1 = OUT, 2 = V_S, 3 = GND

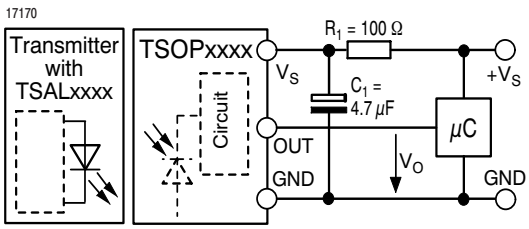
Block Diagram



Parts Table

Part	Carrier Frequency
TSOP32230	30 kHz
TSOP32233	33 kHz
TSOP32236	36 kHz
TSOP32237	36.7 kHz
TSOP32238	38 kHz
TSOP32240	40 kHz
TSOP32256	56 kHz

Application Circuit



R_1 + C_1 recommended to suppress power supply disturbances.

The output voltage should not be hold continuously at a voltage below V_O = 2.0 V by the external circuit.

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Supply Voltage	(Pin 2)	V_S	- 0.3 to + 6.0	V
Supply Current	(Pin 2)	I_S	3	mA
Output Voltage	(Pin 1)	V_O	- 0.3 to (V_S + 0.3)	V
Output Current	(Pin 1)	I_O	10	mA
Junction Temperature		T_j	100	°C
Storage Temperature Range		T_{stg}	- 25 to + 85	°C
Operating Temperature Range		T_{amb}	- 25 to + 85	°C
Power Consumption	($T_{amb} \leq$ 85 °C)	P_{tot}	30	mW
Soldering Temperature	t ≤ 10 s, 1 mm from case	T_{sd}	260	°C

Electrical and Optical Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Supply Current (Pin 2)	E_v = 0	I_{SD}	0.7	1.2	1.5	mA
	E_v = 40 klx, sunlight	I_{SH}		1.3		mA
Supply Voltage		V_S	2.7		5.5	V
Transmission Distance	E_v = 0, test signal see fig.1, IR diode TSAL6200, I_F = 250 mA	d		35		m
Output Voltage Low (Pin 1)	I_{OSL} = 0.5 mA, E_e = 0.7 mW/m², test signal see fig. 1	V_{OSL}			250	mV
Irradiance (30-40 kHz)	V_S = 3 V Pulse width tolerance: $t_{pi} - 5/f_o < t_{po} < t_{pi} + 6/f_o$, test signal see fig.1	$E_{e\ min}$		0.2	0.4	mW/m²
Irradiance (56 kHz)	V_S = 3 V Pulse width tolerance: $t_{pi} - 5/f_o < t_{po} < t_{pi} + 6/f_o$, test signal see fig.1	$E_{e\ min}$		0.3	0.5	mW/m²
Irradiance (30-40 kHz)	V_S = 5 V Pulse width tolerance: $t_{pi} - 5/f_o < t_{po} < t_{pi} + 6/f_o$, test signal see fig.1	$E_{e\ min}$		0.35	0.5	mW/m²
Irradiance (56 kHz)	V_S = 5 V Pulse width tolerance: $t_{pi} - 5/f_o < t_{po} < t_{pi} + 6/f_o$, test signal see fig.1	$E_{e\ min}$		0.45	0.6	mW/m²
Irradiance	$t_{pi} - 5/f_o < t_{po} < t_{pi} + 6/f_o$, test signal see fig. 1	$E_{e\ max}$	30			W/m²
Directivity	Angle of half transmission distance	$\varphi_{1/2}$		± 45		deg

Typical Characteristics (T_{amb} = 25 °C unless otherwise specified)

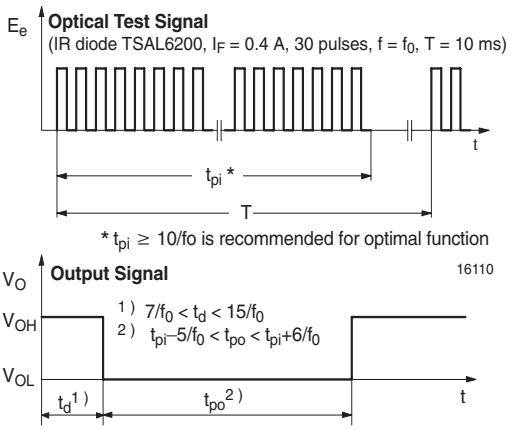


Figure 1. Output Function

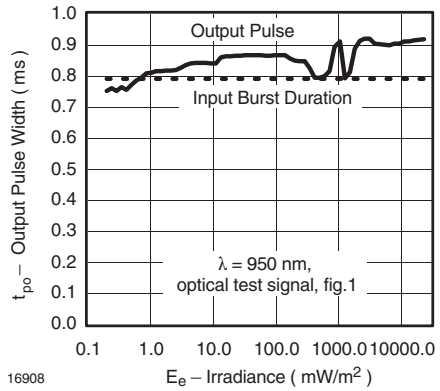


Figure 2. Pulse Length and Sensitivity in Dark Ambient

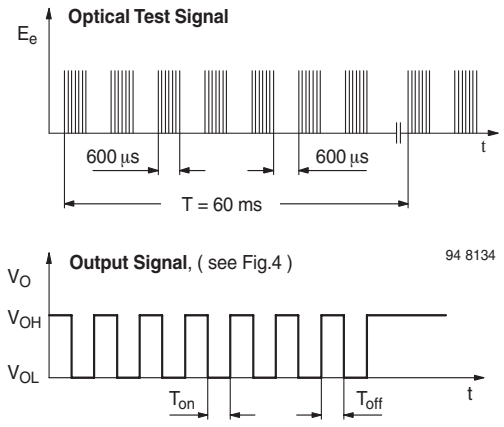


Figure 3. Output Function

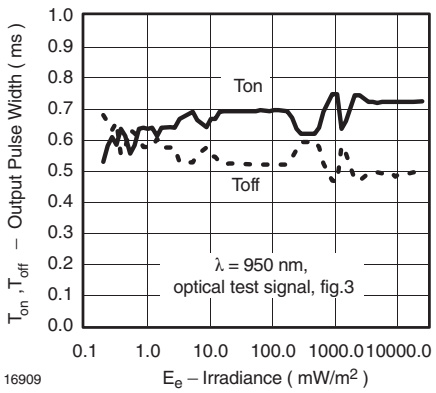


Figure 4. Output Pulse Diagram

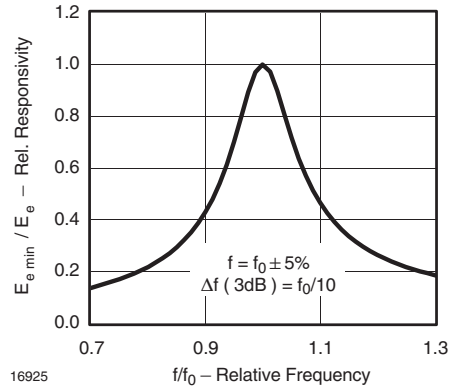


Figure 5. Frequency Dependence of Responsivity

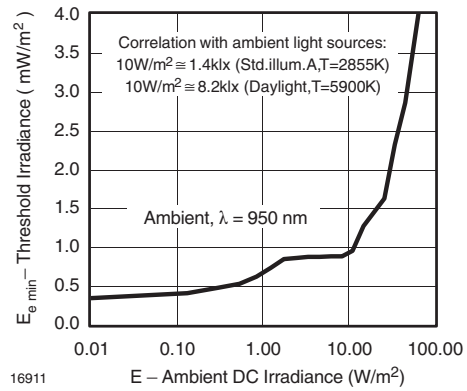


Figure 6. Sensitivity in Bright Ambient

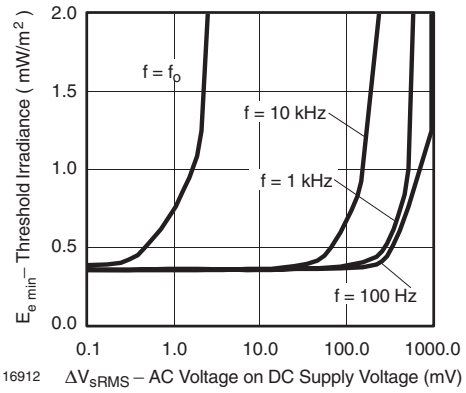


Figure 7. Sensitivity vs. Supply Voltage Disturbances

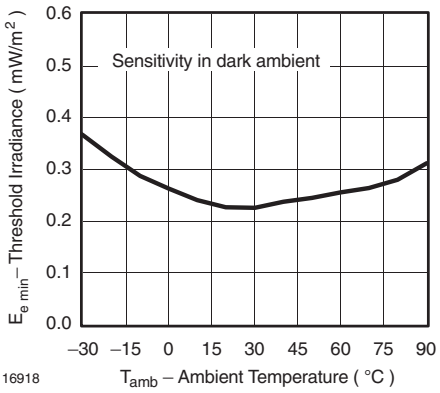


Figure 10. Sensitivity vs. Ambient Temperature

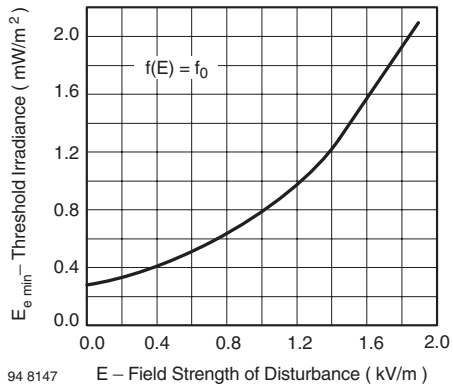


Figure 8. Sensitivity vs. Electric Field Disturbances

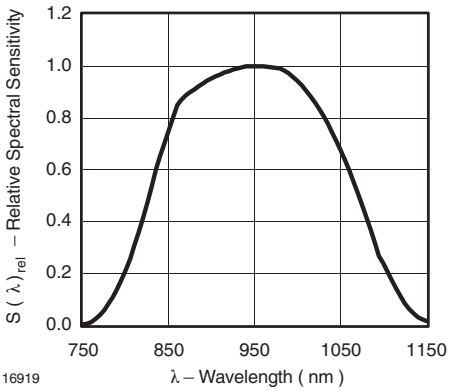


Figure 11. Relative Spectral Sensitivity vs. Wavelength

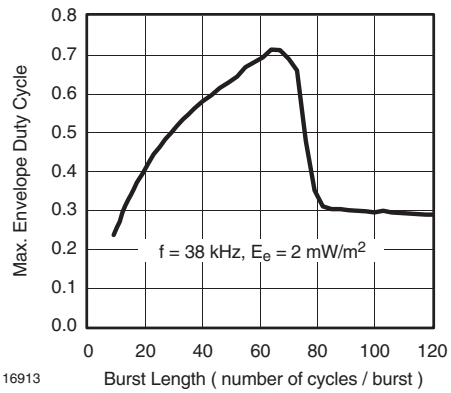


Figure 9. Max. Envelope Duty Cycle vs. Burstlength

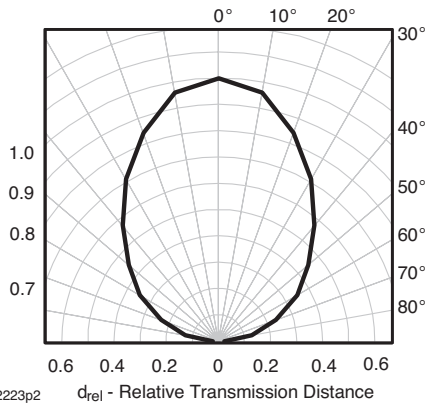


Figure 12. Directivity

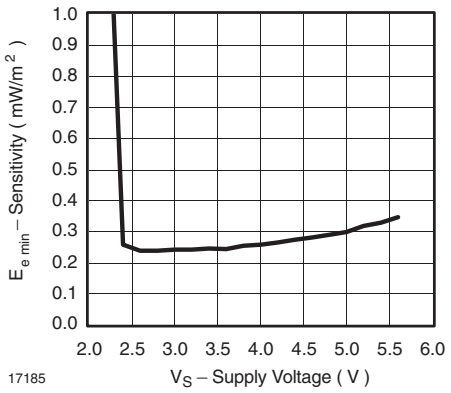


Figure 13. Sensitivity vs. Supply Voltage

Suitable Data Format

The circuit of the TSOP322.. is designed in that way that unexpected output pulses due to noise or disturbance signals are avoided. A bandpass filter, an integrator stage and an automatic gain control are used to suppress such disturbances.

The distinguishing mark between data signal and disturbance signal are carrier frequency, burst length and duty cycle.

The data signal should fulfill the following conditions:

• Carrier frequency should be close to center frequency of the bandpass (e.g. 38 kHz).

• Burst length should be 10 cycles/burst or longer.

• After each burst which is between 10 cycles and 70 cycles a gap time of at least 14 cycles is necessary.

• For each burst which is longer than 1.8 ms a corresponding gap time is necessary at some time in the data stream. This gap time should be at least 4 times longer than the burst.

• Up to 800 short bursts per second can be received continuously.

Some examples for suitable data format are: NEC Code (repetitive pulse), NEC Code (repetitive data), Toshiba Micom Format, Sharp Code, RC5 Code, RC6 Code, R-2000 Code, Sony Code.

When a disturbance signal is applied to the TSOP322.. it can still receive the data signal. However the sensitivity is reduced to that level that no unexpected pulses will occur.

Some examples for such disturbance signals which are suppressed by the TSOP322.. are:

• DC light (e.g. from tungsten bulb or sunlight)

• Continuous signal at 38 kHz or at any other frequency

• Signals from fluorescent lamps with electronic ballast with high or low modulation
(see Figure 14 or Figure 15).

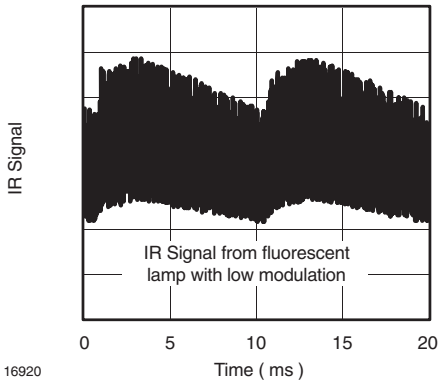


Figure 14. IR Signal from Fluorescent Lamp with low Modulation

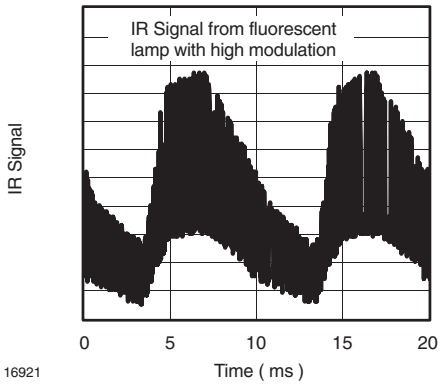
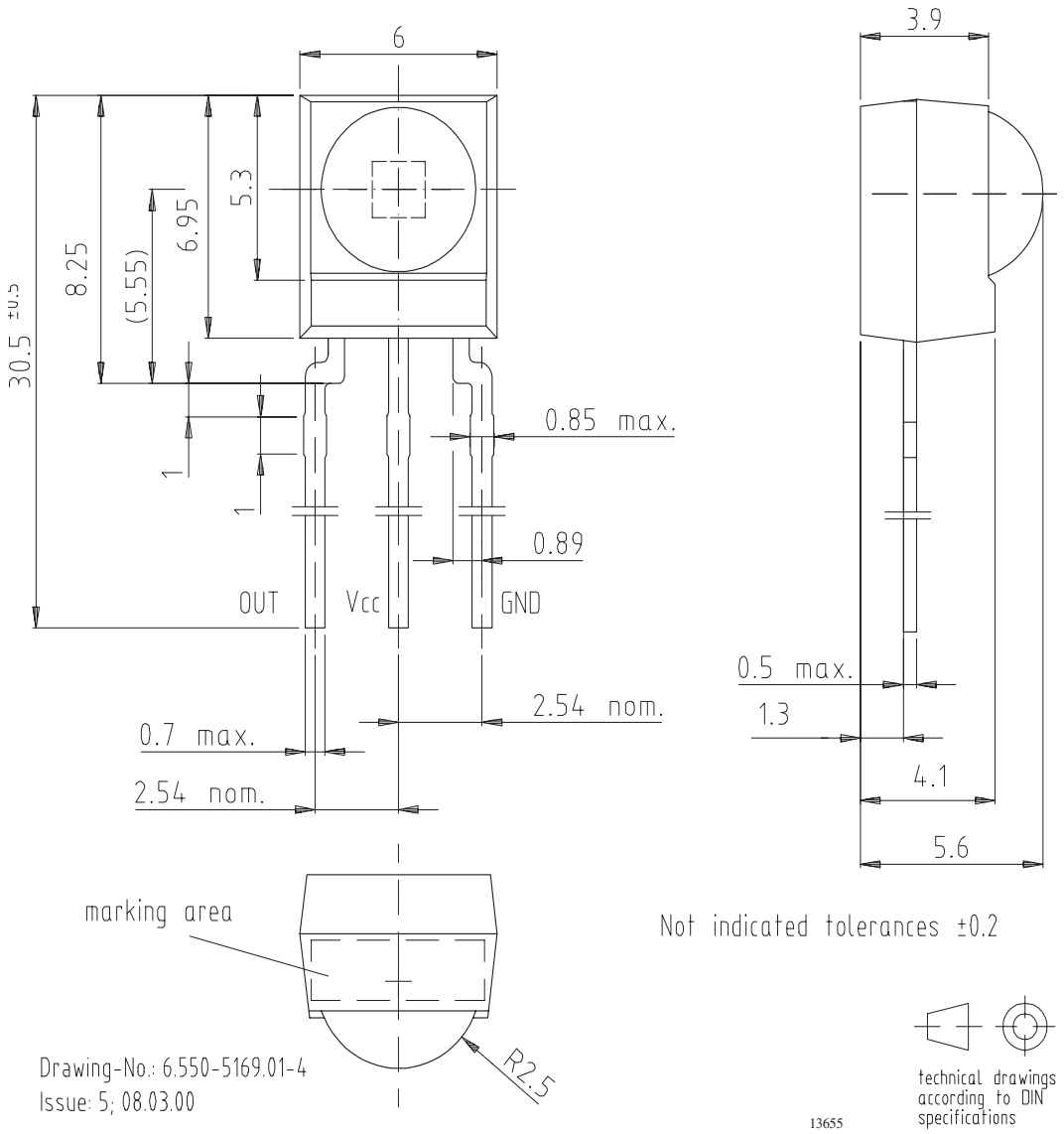


Figure 15. IR Signal from Fluorescent Lamp with high Modulation

Package Dimensions in mm



Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operatingsystems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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